L Number	Hits	Search Text	DB	Time stamp
2	1577	methylsilane or methyl-silane	USPAT;	2004/02/05
			US-PGPUB; EPO; JPO;	16:07
			DERWENT;	
	140166		IBM_TDB	2004/02/05
3	149166	"ch.sub.3"	USPAT; US-PGPUB;	2004/02/05
			EPO; JPO;	
			DERWENT; IBM TDB	
4	1138	"sih.sub.3"	USPAT;	2004/02/05
			US-PGPUB;	13:13
			EPO; JPO; DERWENT;	
			IBM_TDB	
5	426	"ch.sub.3" with "sih.sub.3"	USPAT; US-PGPUB;	2004/02/05
:			EPO; JPO;	
			DERWENT;	:
6	310	"ch.sub.3" near3 "sih.sub.3"	IBM_TDB USPAT;	2004/02/05
	310		US-PGPUB;	16:07
			EPO; JPO; DERWENT;	
			IBM TDB	
7	1731	(methylsilane or methyl-silane ) or	USPAT;	2004/02/05
		("ch.sub.3" near3 "sih.sub.3")	US-PGPUB; EPO; JPO;	13:13
			DERWENT;	
8	0	annealing with ("ch.sub.3" near3	IBM_TDB USPAT;	2004/02/05
0	0	"sih.sub.3")	US-PGPUB;	13:14
			EPO; JPO;	
		·	DERWENT; IBM TDB	
9	3		USPAT;	2004/02/05
		methyl-silane )	US-PGPUB; EPO; JPO;	13:16
			DERWENT;	
11	4	(metal or conductive) with ("ch.sub.3"	IBM_TDB USPAT;	2004/02/05
**	7	near3 "sih.sub.3")	US-PGPUB;	14:13
			EPO; JPO;	
<u>.</u>			DERWENT; IBM TDB	
10	32	'	USPAT;	2004/02/05
		or methyl-silane )	US-PGPUB; EPO; JPO;	13:25
			DERWENT;	
12	6	(("20020187633") or ("5956594") or	IBM_TDB USPAT;	2004/02/05
14	ا	("6383951")).PN.	US-PGPUB;	13:55
			EPO; JPO;	
			DERWENT; IBM TDB	
13	0	("capacitorand6").PN.	USPAT;	2004/02/05
			US-PGPUB; EPO; JPO;	13:55
			DERWENT;	
14	10	capacitor and / lish sub 2" man=2	IBM_TDB	2004/02/05
14	18	capacitor and ("ch.sub.3" near3 "sih.sub.3")	USPAT; US-PGPUB;	14:10
			EPO; JPO;	
			DERWENT; IBM TDB	
L	l	<u> </u>	1	1

15	633	(plasma adj treatment) with ultraviolet	USPAT; US-PGPUB; EPO; JPO;	2004/02/05 14:13
16	0		DERWENT; IBM_TDB USPAT;	2004/02/05
		((plasma adj treatment) with ultraviolet)	US-PGPUB; EPO; JPO; DERWENT; IBM TDB	14:11
17	2	(methylsilane or methyl-silane ) and ((plasma adj treatment) with ultraviolet)	USPAT; US-PGPUB; EPO; JPO;	2004/02/05 14:11
18	71	(metal or conductive) same ((plasma adj treatment) with ultraviolet)	DERWENT; IBM_TDB USPAT; US-PGPUB;	2004/02/05 14:12
10	2400		EPO; JPO; DERWENT; IBM_TDB	2004/02/05
19	2400	plasma near4 ultraviolet	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/02/05 14:56
20	1459	(metal or conductive) and (plasma near4 ultraviolet)	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/02/05
21	158832	(metal or conductive) and capacitor	DERWENT; IBM_TDB USPAT; US-PGPUB;	2004/02/05
22	273	(plasma near4 ultraviolet) and capacitor	EPO; JPO; DERWENT; IBM_TDB USPAT;	2004/02/05
			US-PGPUB; EPO; JPO; DERWENT;	14:15
23	77	(radio adj frequency or rf) and ((plasma adj treatment) with ultraviolet)	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/02/05 14:16
24	8	(radio adj frequency or rf) same ((plasma adj treatment) with ultraviolet)	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/02/05 14:41
		_	DERWENT; IBM TDB	
25	346	(radio adj frequency or rf) same ultraviolet same power	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/02/05 14:55
26	212	plasma and ((radio adj frequency or rf) same ultraviolet same power)	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/02/05 14:42
27	147	plasma same ((radio adj frequency or rf) same ultraviolet same power)	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/02/05 14:42
			DERWENT;	
29	70	(radio adj frequency or rf) same (methylsilane or methyl-silane)	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/02/05 14:55
			DERWENT; IBM_TDB	

20	2.2	/	TICDEM	2004/02/05
28	23	(radio adj frequency or rf) same	USPAT;	2004/02/05
		("ch.sub.3" near3 "sih.sub.3")	US-PGPUB;	14:55
			EPO; JPO;	
			DERWENT;	
3.1	,	/	IBM_TDB	2004/02/05
31	1	("ch.sub.3" near3 "sih.sub.3") same	USPAT;	2004/02/05
		ultraviolet	US-PGPUB;	14:56
			EPO; JPO;	
		,	DERWENT;	
20	4.4		IBM_TDB	2004/02/05
30	. 44	(methylsilane or methyl-silane ) same	USPAT;	2004/02/05
		ultraviolet	US-PGPUB;	16:04
			EPO; JPO;	
			DERWENT;	
22	35		IBM_TDB	2004/02/05
32	35	inductively with plasma with ultraviolet	USPAT;	2004/02/05
			US-PGPUB;	16:06
			EPO; JPO;	[
			DERWENT;	
,,	0	/mothulailane on mothulasilane\ assa	IBM_TDB	3004/03/05
33	ا ا	(methylsilane or methyl?silane) same aluminum same ultraviolet	USPAT;	2004/02/05
		atuminum same ultraviolet	US-PGPUB; EPO; JPO;	10:00
			DERWENT;	
	-		IBM TDB	
24	310	"ch.sub.3" near3 "sih.sub.3"	USPAT;	2004/02/05
34	310	cn.sub.5 nears sin.sub.5	US-PGPUB;	16:07
			EPO; JPO;	10.07
			DERWENT;	
•			IBM TDB	**************************************
35	o	(("ch.sub.3" near3 "sih.sub.3")) same	USPAT;	2004/02/05
33	١	aluminum same ultraviolet	US-PGPUB;	16:08
		aruminum same urcraviorec	EPO; JPO;	10.00
			DERWENT;	
			IBM TDB	
36	o	("ch.sub.3" near3 "sih.sub.3") same	USPAT;	2004/02/05
		aluminum same ultraviolet	US-PGPUB;	16:08
		araminam samo artitavioret	EPO; JPO;	
			DERWENT;	
			IBM TDB	
37	0	("ch.sub.3" near3 "sih.sub.3") same	USPAT;	2004/02/05
		electrode same ultraviolet	US-PGPUB;	16:08
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
38	o	(methylsilane or methyl?silane) same	USPAT;	2004/02/05
		electrode same ultraviolet	US-PGPUB;	16:08
		·	EPO; JPO;	
			DERWENT;	
			IBM TDB	
39	2	(methylsilane or methyl?silane) same	USPAT;	2004/02/05
		metal same ultraviolet	US-PGPUB;	16:09
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	